Triacs Silicon Bidirectional Thyristors

Designed primarily for full-wave ac control applications, such as motor controls, heating controls or dimmers; or wherever full-wave, silicon gate-controlled devices are needed.

Features

- Uniform Gate Trigger Currents in Three Quadrants, Q1, Q2, and Q3
- High Commutating di/dt and High Immunity to dv/dt @ 125°C
- Minimizes Snubber Networks for Protection
- Blocking Voltage to 800 Volts
- On-State Current Rating of 12 Amperes RMS at 80°C
- High Surge Current Capability 100 Amperes
- Industry Standard TO-220AB Package for Ease of Design
- Glass Passivated Junctions for Reliability and Uniformity
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS (T, I = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) ($T_J = -40$ to 125°C, Sine Wave, 50 to 60 Hz, Gate Open)	V _{DRM,} V _{RRM}		V
MAC12HCDG MAC12HCMG MAC12HCNG		400 600 800	
On-State RMS Current (All Conduction Angles; $T_C = 80^{\circ}C$)	I _{T(RMS)}	12	A
Peak Non-Repetitive Surge Current (One Full Cycle, 60 Hz, T _J = 125°C)	I _{TSM}	100	A
Circuit Fusing Consideration (t = 8.33 ms)	l ² t	41	A ² sec
Peak Gate Power (Pulse Width \leq 1.0 µs, T _C = 80°C)	P _{GM}	16	W
Average Gate Power (t = 8.3 ms, $T_C = 80^{\circ}C$)	P _{G(AV)}	0.35	W
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

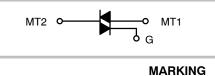
1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



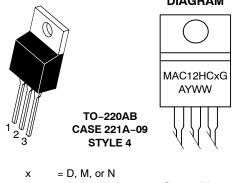
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TRIACS **12 AMPERES RMS** 400 thru 800 VOLTS







= Assembly Location (Optional)* А

= Year

Y

\\/\// = Work Week

G = Pb-Free Package

* The Assembly Location code (A) is optional. In cases where the Assembly Location is stamped on the package the assembly code may be blank.

PIN ASSIGNMENT			
1	Main Terminal 1		
2	Main Terminal 2		
3	Gate		
4	Main Terminal 2		

ORDERING INFORMATION

Device	Package	Shipping		
MAC12HCDG	TO-220AB (Pb-Free)	50 Units / Rail		
MAC12HCMG	TO-220AB (Pb-Free)	50 Units / Rail		
MAC12HCNG	TO–220AB (Pb–Free)	50 Units / Rail		

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case Junction-to-Ambient	$R_{ extsf{ heta}JC}$ $R_{ heta}JA$	2.2 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds		260	°C

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted; Electricals apply in both directions)

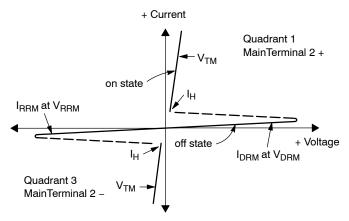
Characteristic		Symbol	Min	Тур	Max	Unit
DFF CHARACTERISTICS		4				
Peak Repetitive Blocking Current (V_D = Rated V_{DRM} , V_{RRM} , Gate Open)	T _J = 25°C T _J = 125°C	I _{DRM} , I _{RRM}			0.01 2.0	mA
ON CHARACTERISTICS						
Peak On-State Voltage (Note 2) ($I_{TM} = \pm 17 \text{ A}$)		V _{TM}	_	_	1.85	V
Gate Trigger Current (Continuous dc) ($V_D = 12 V$, $R_L = 100 \Omega$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)		I _{GT}	10 10 10	- - -	50 50 50	mA
Holding Current (V_D = 12 V, Gate Open, Initiating Current = ±150 mA)		Чн	_	_	60	mA
Latch Current (V _D = 12 V, I_G = 50 mA) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)		ΙL	- - -	- - -	60 80 60	mA
Gate Trigger Voltage (Continuous dc) (V _D = 12 V, R _L = 100 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)		V _{GT}	0.5 0.5 0.5	- - -	1.5 1.5 1.5	V
DYNAMIC CHARACTERISTICS		4				
Rate of Change of Commutating Current (V _D = 400 V, I _{TM} = 4.4 A, Commutating dv/dt = 18 V/ μ s, Gate Open, T _J = 125°C, f = 250 Hz, C _L = 10 μ F, L _L = 40 mH, with Snubber)	,	(di/dt) _c	15	_	-	A/ms
Critical Rate of Rise of Off-State Voltage (V_D = Rated V_{DRM} , Exponential Waveform, Gate Open, T_J = 125°C)		dv/dt	600	_	-	V/µs
Repetitive Critical Rate of Rise of On-State Current IPK = 50 A; PW = 40 μ sec; diG/dt = 200 mA/ μ sec; f = 60 Hz		di/dt	-	-	10	A/μs

2. Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.

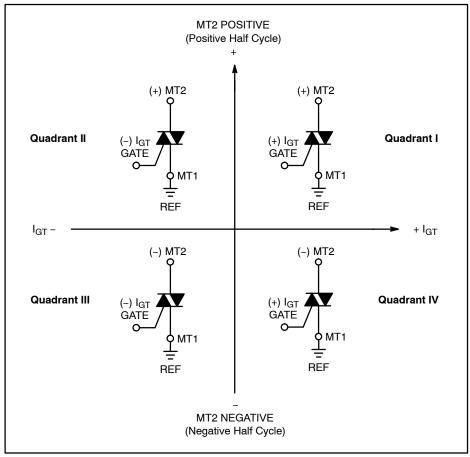
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Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter	
V _{DRM}	Peak Repetitive Forward Off State Voltage	
I _{DRM}	Peak Forward Blocking Current	
V _{RRM}	Peak Repetitive Reverse Off State Voltage	
I _{RRM}	Peak Reverse Blocking Current	
V _{TM}	Maximum On State Voltage	
I _H	Holding Current	



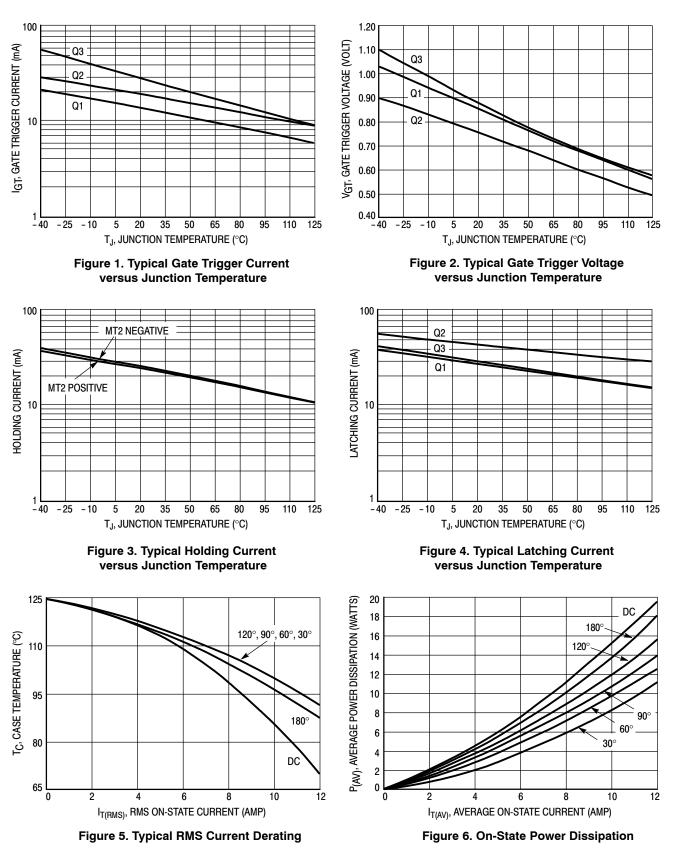
Quadrant Definitions for a Triac



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

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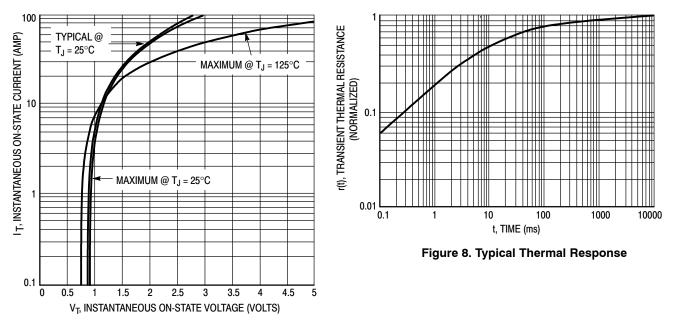
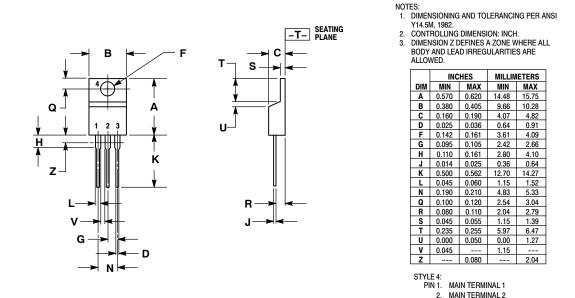


Figure 7. Typical On-State Characteristics

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PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AG**



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